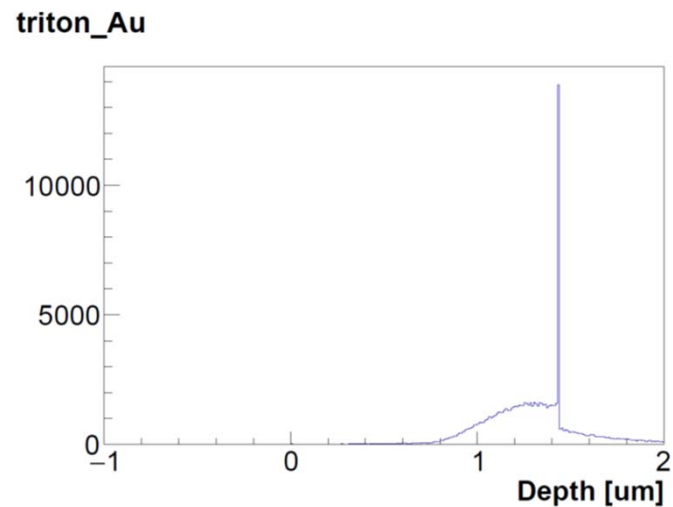


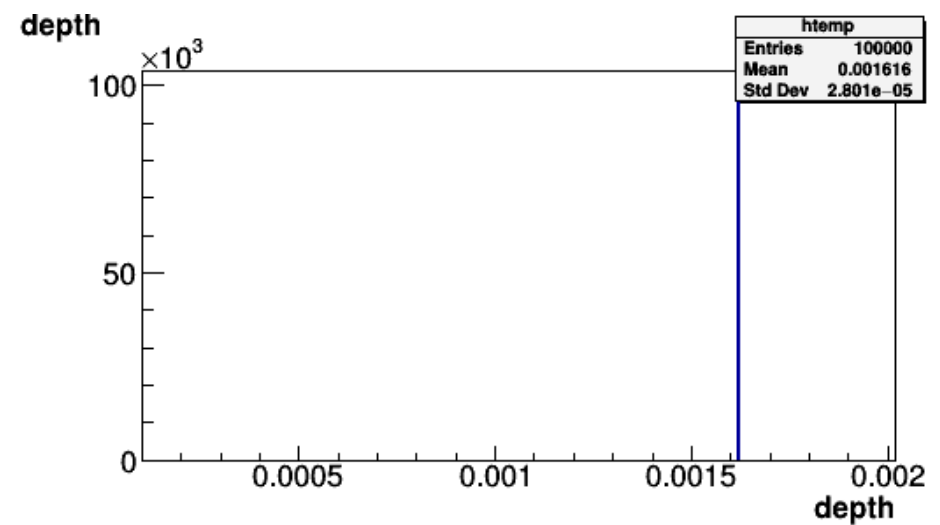
Geant4 Simulation (triton implantation)

200 keV



- Expected depth:
1.287 μm

191 keV

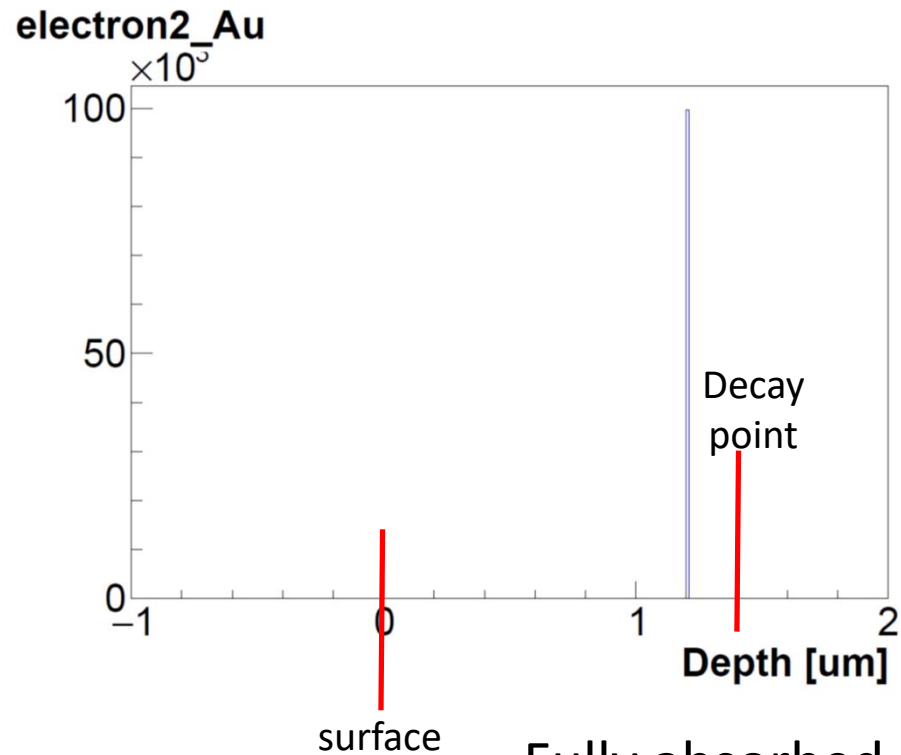


1.616 μm

: GEANT4 Simulation electron

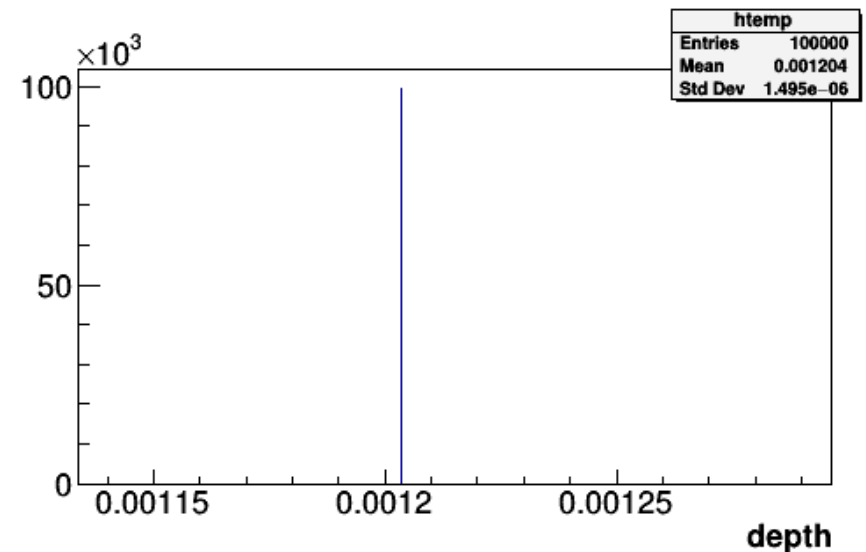
Old version

(200 keV triton, 18 keV e-)



New version

(191 keV triton, 18.6 keV e-)



Fully absorbed by the absorber metal